

# **Device Modeling Report**

**COMPONENTS:**

**DIODE/ SCHOTTKY RECTIFIER / STANDARD**

**PART NUMBER: GSQ05A03LB**

**MANUFACTURER: NIEC**

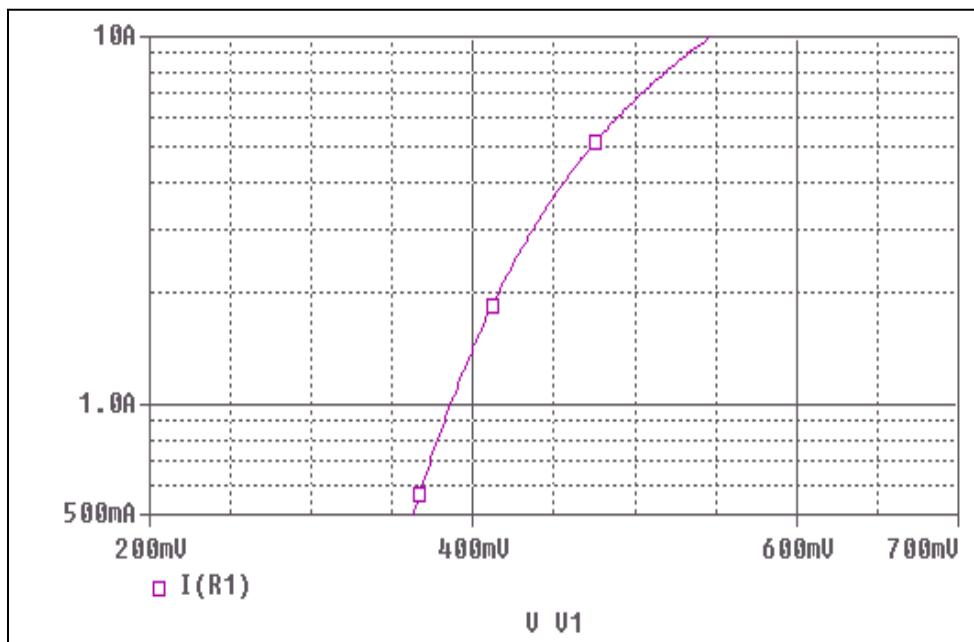


**Bee Technologies Inc.**

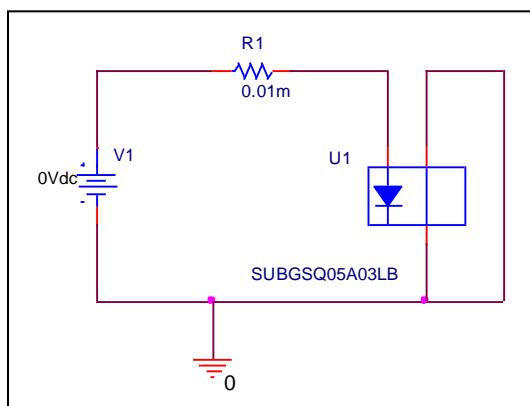
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

Circuit Simulation Result

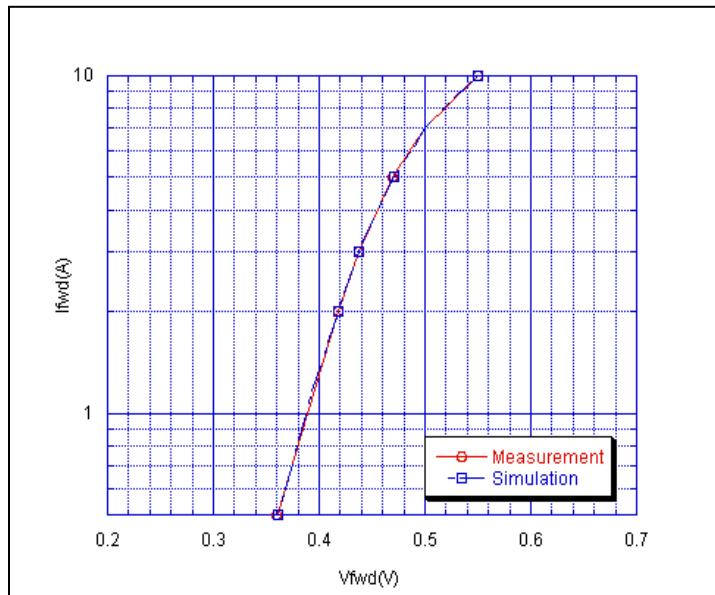


Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

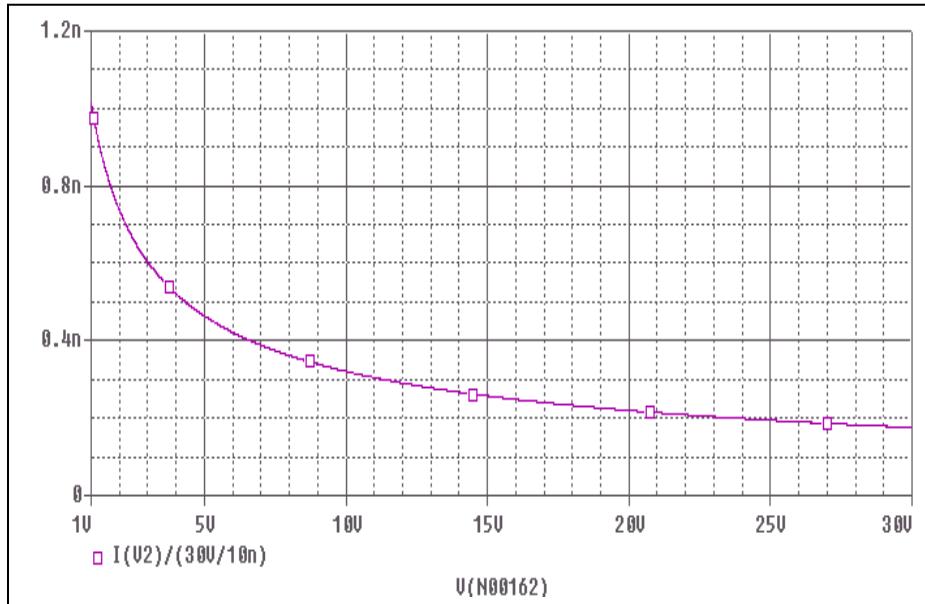


Simulation Result

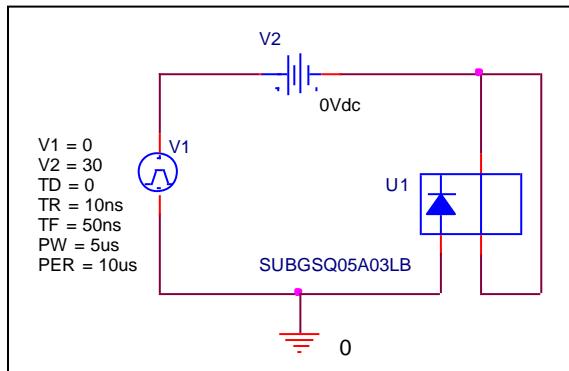
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
1	0.389	0.387	-0.51
2	0.418	0.417	-0.24
5	0.470	0.471	0.21
10	0.550	0.549	-0.18

## Junction Capacitance Characteristic

### Circuit Simulation Result

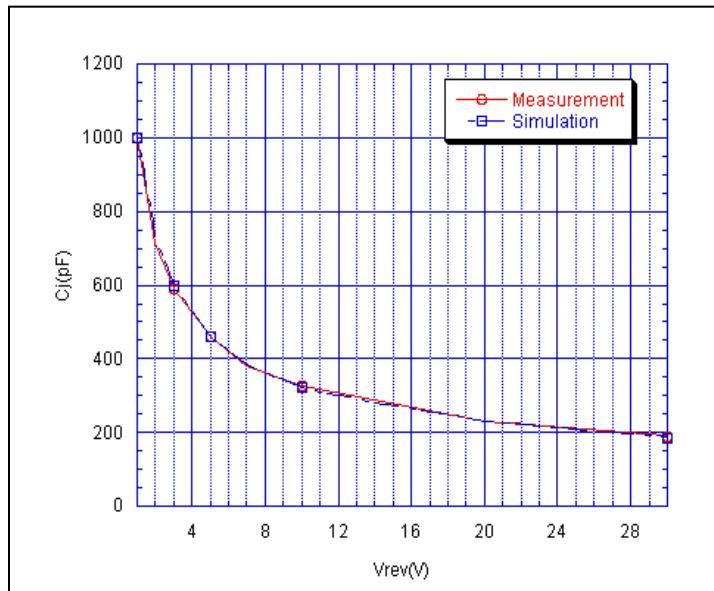


### Evaluation Circuit



## Comparison Graph

Circuit Simulation Result



Simulation Result

$V_{rev}$ (V)	$C_j$ (pF) Measurement	$C_j$ (pF) Simulation	%Error
1	1000.000	999.000	-0.10
2	715.000	722.000	0.98
5	460.000	461.000	0.22
10	325.000	324.000	-0.31
20	230.000	229.000	-0.43
30	190.000	185.000	-2.63